74LVTN16245B

3.3 V 16-bit transceiver; 3-state

Rev. 02 — 23 March 2010

Product data sheet

1. **General description**

The 74LVTN16245B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

This device is a 16-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The control function implementation minimizes external timing requirements. The device features an output enable input (nOE) for easy cascading and a direction input (nDIR) for direction control.

2. Features and benefits

- 16-bit bus interface
- 3-state buffers
- Output capability: +64 mA and -32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Power-up 3-state
- Live insertion and extraction permitted
- No bus current loading when output is tied to 5 V bus
- Latch-up protection
 - ◆ JESD78B Class II exceeds 500 mA
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V

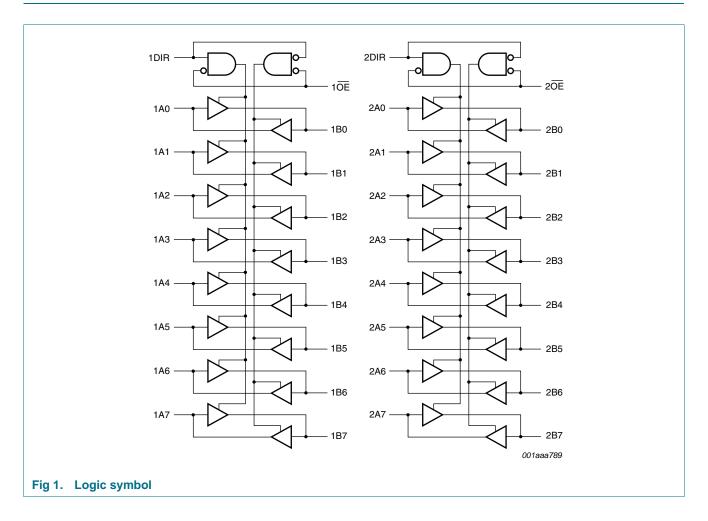
3. Ordering information

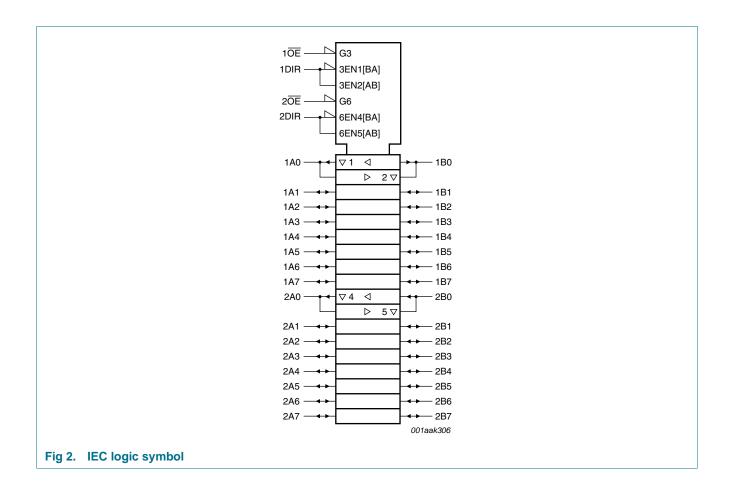
Table 1. **Ordering information**

Type number	Package							
	Temperature range	Name	Description	Version				
74LVTN16245BDGG	–40 °C to +85 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1				
74LVTN16245BBQ	–40 °C to +85 °C	HXQFN60U	plastic thermal enhanced extremely thin quad flat package; no leads; 60 terminals; UTLP based; body $4\times6\times0.5~\text{mm}$	SOT1134-1				



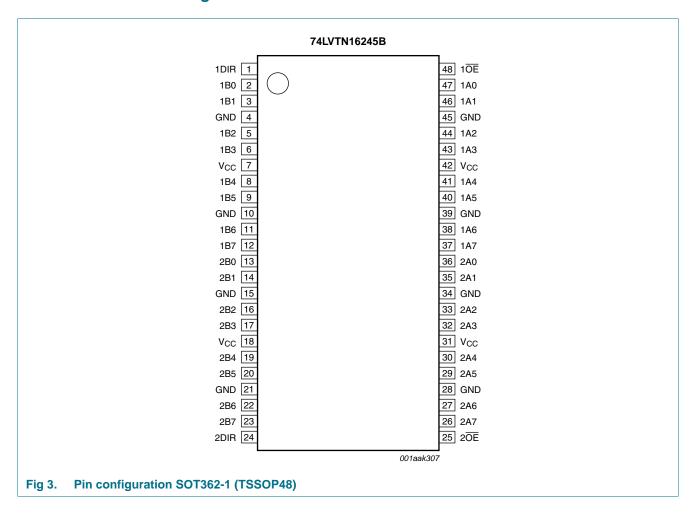
4. Functional diagram





5. Pinning information

5.1 Pinning



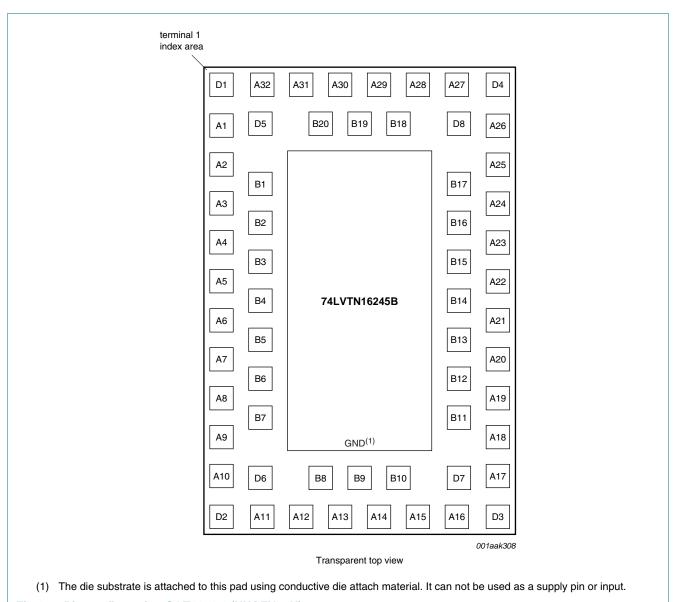


Fig 4. Pin configuration SOT1134-1 (HXQFN60U)

5.2 Pin description

Table 2. Pin description

Symbol	Pin		Description
	SOT362-1	SOT1134-1	_
1DIR, 2DIR	1, 24	A30, A13	direction control input
1B0 to 1B7	2, 3, 5, 6, 8, 9, 11, 12	B20, A31, D5, D1, A2, B2, B3, A5	data input/output
2B0 to 2B7	13, 14, 16, 17, 19, 20, 22, 23	A6, B5, B6, A9, D2, D6, A12, B8	data input/output
GND	4, 10, 15, 21, 28, 34, 39, 45	A32, A3, A8, A11, A16, A19, A24, A27	ground (0 V)
V _{CC}	7, 18, 31, 42	A1, A10, A17, A26	supply voltage
10E, 20E	48, 25	A29, A14	output enable input (active LOW)
2A0 to 2A7	36, 35, 33, 32, 30, 29, 27, 26	A21, B13, B12, A18, D3, D7, A15, B10	data input/output
1A0, to 1A7	47, 46, 44, 43, 41, 40, 38, 37	B18, A28, D8, D4, A25, B16, B15, A22	data input/output
n.c.	-	A4, A7, A20, A23, B1, B4, B7, B9, B11, B14, B17, B19	not connected

6. Functional description

Table 3. Function table [1]

		Input/output		
nOE	nDIR	nAn	nBn	
L	L	output nAn = nBn	input	
L	Н	input	output $nBx = nAx$	
Н	X	Z	Z	

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage		<u>[1]</u> –0.5	+7.0	V
Vo	output voltage	output in OFF-state or HIGH-state	[<u>1</u>] -0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		[2] _	150	°C

74LVTN16245B_2

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Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
P_{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$			
		TSSOP48 package	[3] _	500	mW
		HXQFN60U package	<u>[4]</u> _	1000	mW

^[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		2.7	-	3.6	V
VI	input voltage		0	-	5.5	V
V_{IH}	HIGH-level input voltage		2.0	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.8	V
I _{OH}	HIGH-level output current		-32	-	-	mA
I _{OL}	LOW-level output current	none	-	-	32	mA
		current duty cycle \leq 50 %; $f_i \geq$ 1 kHz	-	-	64	mA
T _{amb}	ambient temperature	in free-air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	outputs enabled	-	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -4$	40 °C to +85 °C					
V_{IK}	input clamping voltage	$V_{CC} = 2.7 \text{ V}; I_{IK} = -18 \text{ mA}$	-1.2	-0.85	-	V
V_{OH}	HIGH-level output voltage	I_{OH} = $-100 \mu A$; V_{CC} = 2.7 V to 3.6 V	$V_{CC}-0.2$	V_{CC}	-	V
		$I_{OH} = -8 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.4	2.5	-	V
		$I_{OH} = -32 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.0	2.3	-	V
V_{OL}	LOW-level output voltage	V _{CC} = 2.7 V				
		I _{OL} = 100 μA	-	0.07	0.2	V
		I _{OL} = 24 mA	-	0.3	0.5	V
		V _{CC} = 3.0 V				
		I _{OL} = 16 mA	-	0.25	0.4	V
		I _{OL} = 32 mA	-	0.3	0.5	V
		I _{OL} = 64 mA	-	0.4	0.55	V

74LVTN16245B_2

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^[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

^[3] Above 60 °C the value of Ptot derates linearly with 5.5 mW/K.

^[4] Above 70 °C the value of P_{tot} derates linearly with 1.8 mW/K.

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
l _l	input leakage current	control pins				
OFF LO ($V_{CC} = 3.6 \text{ V}; V_I = V_{CC} \text{ or GND}$	-	0.1	±1	μΑ
		$V_{CC} = 0 \text{ V or } 3.6 \text{ V}; V_{I} = 5.5 \text{ V}$	-	0.1	10	μΑ
		input/output data pins; V _{CC} = 3.6 V	<u>[2]</u>			
		V _I = 5.5 V	-	0.1	20	μΑ
		$V_I = V_{CC}$	-	0.5	10	μΑ
		V _I = 0 V	-5	-0.1	-	μΑ
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}$; V_{I} or $V_{O} = 0 \text{ V}$ to 4.5 V	-	0.1	±100	μΑ
I _{LO}	output leakage current	output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5 \text{ V}$; $V_{CC} = 3.0 \text{ V}$	-	75	125	μА
I _{O(pu/pd)}	power-up/power-down output current	$V_{CC} \le 1.2 \text{ V}; V_O = 0.5 \text{ V} \text{ to } V_{CC};$ $V_I = \text{GND or } V_{CC}; \text{ nOE} = \text{don't care}$	[3]	40	±100	μА
I _{CC}	supply current	V_{CC} = 3.6 V; V_I = GND or V_{CC} ; I_O = 0 A				
		output HIGH	-	0.07	0.12	mΑ
		output LOW	-	4.0	6.0	mA
		outputs disabled	<u>[4]</u> _	0.07	0.12	mΑ
Δl _{CC}	additional supply current	per input pin; V_{CC} = 3.0 V to 3.6 V; one input at V_{CC} – 0.6 V other inputs at V_{CC} or GND	<u>[5]</u> _	0.1	0.2	mA
Cı	input capacitance	pins nDIR and n \overline{OE} , V _O = 0 V or 3.0 V	-	3	-	pF
$C_{io(off)}$	off-state input/output capacitance	pins nAn and nBn, outputs disabled; $V_O = GND$ or V_{CC}	-	9	-	pF

^[1] Typical values are measured at $V_{CC} = 3.3 \text{ V}$ and at $T_{amb} = 25 \,^{\circ}\text{C}$.

^[2] Unused pins at V_{CC} or GND.

^[3] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms. From V_{CC} = 1.2 V to V_{CC} = 3.3 V \pm 0.3 V a transition time of 100 μ s is permitted. This parameter is valid for T_{amb} = 25 °C only.

^[4] I_{CC} is measured with outputs pulled to V_{CC} or GND.

^[5] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

10. Dynamic characteristics

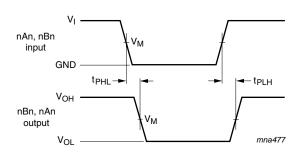
Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$T_{amb} = -40$	°C to +85 °C					
t _{PLH}	LOW to HIGH propagation delay	nAn to nBn or nBn to nAn; see Figure 5				
		V _{CC} = 2.7 V	-	-	3.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	1.9	3.3	ns
t _{PHL}	HIGH to LOW propagation delay	nAn to nBn or nBn to nAn; see Figure 5				
		V _{CC} = 2.7 V	-	-	3.5	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	1.7	3.3	ns
t _{PZH}	OFF-state to HIGH propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.8	4.5	ns
t _{PZL}	OFF-state to LOW propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.0	2.8	4.1	ns
t _{PHZ}	HIGH to OFF-state propagation delay	nOE to nAn or nBn; see Figure 6				
		V _{CC} = 2.7 V	-	-	5.7	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	3.2	5.1	ns
t _{PLZ}	LOW to OFF-state propagation delay	nOE to nAn or nBn; see <u>Figure 6</u>				
		$V_{CC} = 2.7 \text{ V}$	-	-	4.6	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.5	3.0	4.6	ns

^[1] Typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 $^{\circ}C.$

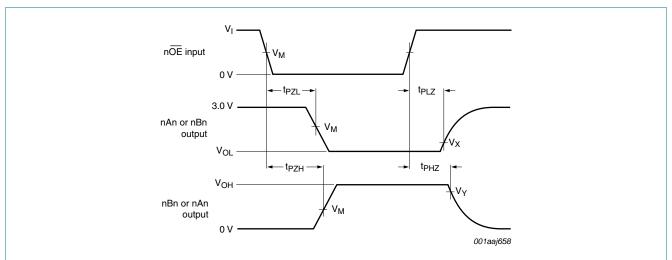
11. Waveforms



Measurements points are given in <u>Table 8</u>.

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. Propagation delay input (nAn, nBn) to output (nBn, nAn)



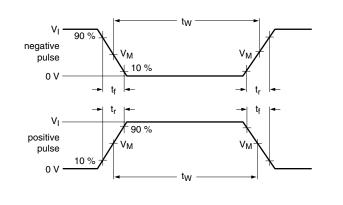
Measurements points are given in Table 8.

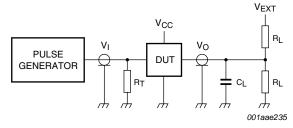
 $\ensuremath{V_{OL}}$ and $\ensuremath{V_{OH}}$ are typical voltage output levels that occur with the output load.

Fig 6. Enable and disable times

Table 8. Measurement points

Input	Output		
V_{M}	V _M	V _X	V _Y
1.5 V	1.5 V	V _{OL} + 0.3 V	$V_{OH} - 0.3 V$





Test data is given in Table 9.

Definitions test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 7. Load circuit for measuring switching times

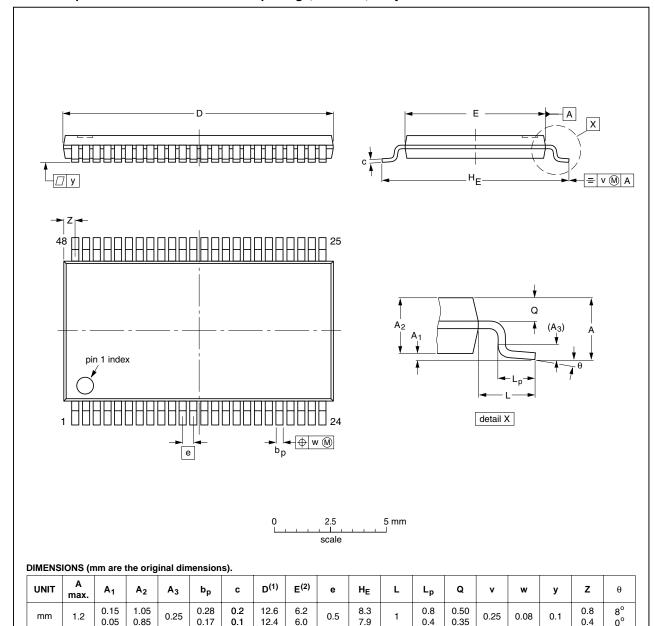
Table 9. Test data

Input			Load		V _{EXT}			
V_{I}	f _i	t _W	t _r , t _f	C _L	R_L	t _{PHZ} , t _{PZH}	t_{PLZ} , t_{PZL}	t _{PLH} , t _{PHL}
2.7 V	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500Ω	GND	6 V	open

12. Package outline

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION IEC JEE	REFER	ENCES	EUROPEAN	ICCUIT DATE	
	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT362-1		MO-153			99-12-27 03-02-19

Fig 8. Package outline SOT362-1 (TSSOP48)

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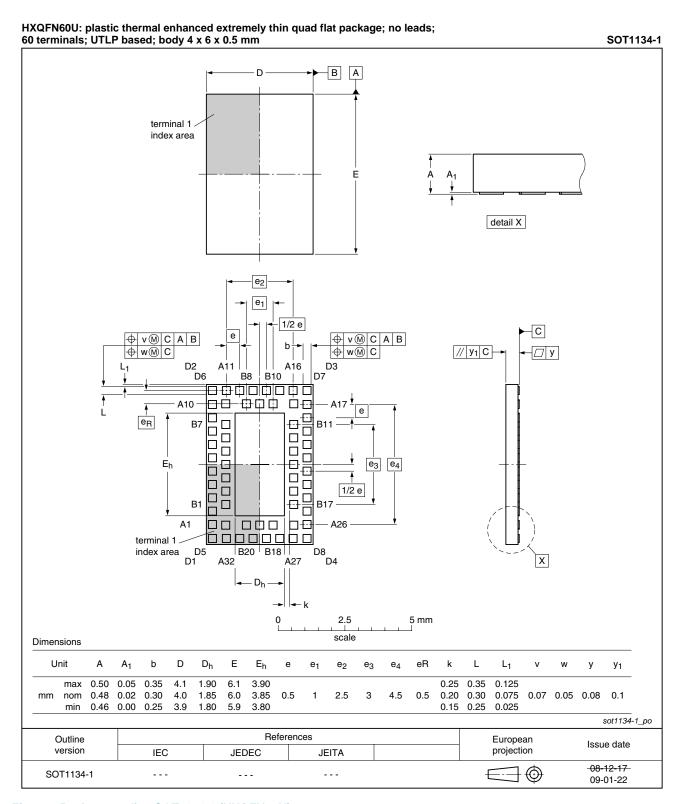


Fig 9. Package outline SOT1134-1 (HXQFN60U)

74LVTN16245B_2

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13. Abbreviations

Table 10. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVTN16245B_2	20100323	Product data sheet	-	74LVTN16245B_1
Modifications:	 74LVTN16245BBQ changed from HUQFN60U (SOT1025-1) to HXQFN60U (SOT1134-1) package. 			
74LVTN16245B_1	20090729	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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15 of 17

74LVTN16245B

3.3 V 16-bit transceiver; 3-state

16. Contact information

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17. Contents

1	General description
2	Features and benefits
3	Ordering information 1
4	Functional diagram 2
5	Pinning information 4
5.1	Pinning
5.2	Pin description 6
6	Functional description 6
7	Limiting values 6
8	Recommended operating conditions 7
9	Static characteristics 7
10	Dynamic characteristics 9
11	Waveforms
12	Package outline 12
13	Abbreviations 14
14	Revision history 14
15	Legal information
15.1	Data sheet status
15.2	Definitions
15.3	Disclaimers
15.4	Trademarks
16	Contact information 16
17	Contents

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